

**DRV8818** 

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#### ZHCS276B-SEPTEMBER 2011-REVISED OCTOBER 2012

## 步进电机控制器 IC

### 查询样品: DRV8818

## 特性

- 脉宽调制 (PWM) 微步进电机驱动器
  - 内置微步进分度器
  - 每绕组高达 2.5-A 电流
  - 微步进分度器提供高达 1/8 步长运行
  - 0.37Ω (HS + LS) 低金属氧化物场效应晶体管 (MOSFET) 接通电阻(25°时)
  - 可编程混合衰退、消隐和关闭时间
- 对具有较低 R<sub>ds (接通)</sub>的 DRV8811 进行引脚兼容升级

• 耐热增强型表面贴装式封装

应用

- 打印机
- 纺织机械
- 定位/跟踪
- 工厂自动化
- 机器人技术

## 说明/订购信息

DRV8818 可为打印机、扫描仪以及其它自动化设备应用提供集成型电机驱动器解决方案。 此器件具有两个 H 桥驱 动器以及步用于控制步进电机的微步进分度器逻辑。

每个输出驱动器块包含被配置为全 H 桥的 N 通道功率MOSFET 以驱动电机绕组。

一个简单的步进/方向接口可轻松连接到控制器电路。引脚支持按全步进、半步进、四分之一步进或八分之一步进 模式配置电机。衰退模式和脉宽调制(PWM)关闭时间均可编程。

内部关断功能用于实现过流保护、短路保护、欠电压闭锁和过温保护。

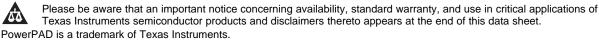
DRV8818 采用PowerPAD<sup>™</sup> 28 引脚带散热片的薄型小尺寸(HTSSOP) 封装,此封装具有PowerPAD<sup>™</sup> (环境 友好:符合RoHS 标准且无铅/无卤素)

| 封装 <sup>(2)</sup>        |            | 可订购部件号      | 正面标记    |
|--------------------------|------------|-------------|---------|
|                          | 2000 卷带式包装 | DRV8818PWPR |         |
| PowerPAD™ (HTSSOP) – PWP | 50 管式封装    | DRV8818PWP  | DRV8818 |

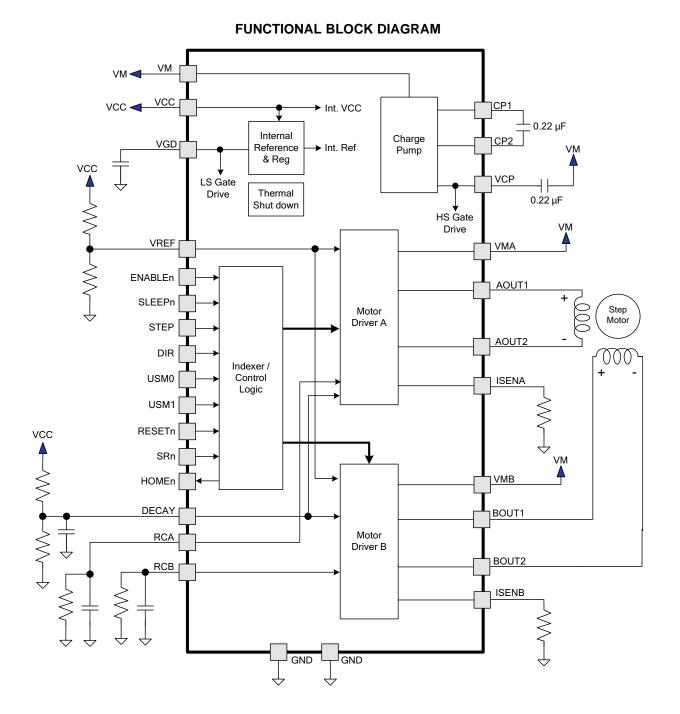
订购信息(1)

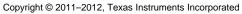
(1) 要获得最新的封装和订货信息,请参阅本文档末尾的封装选项附录,或者登录 TI 的网站 www.ti.com.

(2) 封装图样、热数据和符号可登录 www.ti.com/packaging 获取。









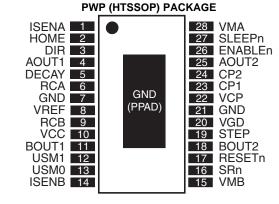
| NAME    | NO.   | I/O <sup>(1)</sup> | DESCRIPTION                           | EXTERNAL COMPONENTS OR CONNECTIONS   |
|---------|-------|--------------------|---------------------------------------|--|
|         | NO.   | 1/0                |                                       | ND GROUND  |
| GND     | 7, 21 | -                  | Device ground                         |  |
| VMA     | 28    | -                  | Bridge A power supply                 | Connect to motor supply (8 V to 35 V). Both pins must be connected to same supply.   |
| VMB     | 15    | -                  | Bridge B power supply                 | Connect to motor supply (8 V to 35 V). Both pins must be connected to same supply.   |
| VCC     | 10    | -                  | Logic supply voltage                  | Connect to 3-V to 5-V logic supply. Bypass to GND with a 0.1- $\mu F$ ceramic capacitor.   |
| CP1     | 23    | IO                 | Charge pump flying capacitor          | Connect a 0.22-µF capacitor between CP1 and CP2.   |
| CP2     | 24    | IO                 | Charge pump flying capacitor          | Connect a 0.22-µF capacitor between CP1 and CP2.   |
| VCP     | 22    | IO                 | High-side gate drive voltage          | Connect a 0.22- $\mu$ F ceramic capacitor to V <sub>M</sub> .  |
| VGD     | 20    | IO                 | Low-side gate drive voltage           | Bypass to GND with a 0.22-µF ceramic capacitor.  |
|         |       |                    | CON                                   | NTROL  |
| ENABLEn | 26    | I                  | Enable input                          | Logic high to disable device outputs, logic low to enable outputs. Weak internal pullup to VCC.  |
| SLEEPn  | 27    | I                  | Sleep mode input                      | Logic high to enable device, logic low to enter low-power sleep mode.<br>Weak internal pulldown.   |
| DECAY   | 5     | I                  | Decay mode select                     | Voltage applied sets decay mode - see motor driver description for details. Bypass to GND with a 0.1-µF ceramic capacitor. Weak internal pulldown. |
| STEP    | 19    | I                  | Step input                            | Rising edge causes the indexer to move one step. Weak internal pulldown.   |
| DIR     | 3     | I                  | Direction input                       | Level sets the direction of stepping. Weak internal pulldown.  |
| USM0    | 13    | I                  | Microstep mode 0                      | USM0 and USM1 set the step mode - full step, half step, quarter step, or eight microsteps/step. Weak internal pulldown.                            |
| USM1    | 12    | I                  | Microstep mode 1                      | USM0 and USM1 set the step mode - full step, half step, quarter step, or eight microsteps/step. Weak internal pulldown.                            |
| RESETn  | 17    | I                  | Reset input                           | Active-low reset input initializes the indexer logic and disables the H-<br>bridge outputs. Weak internal pullup to VCC.                           |
| SRn     | 16    | I                  | Sync. Rect. enable input              | When active low, synchronous rectification is enabled. Weak internal pulldown.   |
| VREF    | 8     | I                  | Current set reference input           | Reference voltage for winding current set  |
| RCA     | 6     | Ι                  | Bridge A blanking and off time adjust | Connect a parallel resistor and capacitor to GND - see motor driver description for details.   |
| RCB     | 9     | I                  | Bridge B blanking and off time adjust | Connect a parallel resistor and capacitor to GND - see motor driver description for details.   |
| ISENA   | 1     | -                  | Bridge A ground / Isense              | Connect to current sense resistor for bridge A   |
| ISENB   | 14    | -                  | Bridge B ground / Isense              | Connect to current sense resistor for bridge B   |
|         |       |                    | OUT                                   | TPUTS  |
| AOUT1   | 4     | 0                  | Bridge A output 1                     | Connect to bipolar stepper motor winding   |
| AOUT2   | 25    | 0                  | Bridge A output 2                     | Positive current is AOUT1 $\rightarrow$ AOUT2  |
| BOUT1   | 11    | 0                  | Bridge B output 1                     | Connect to bipolar stepper motor winding   |
| BOUT2   | 18    | 0                  | Bridge B output 2                     | Positive current is BOUT1 $\rightarrow$ BOUT2  |
| HOMEn   | 2     | 0                  | Home position                         | Logic low when at home state of step table, logic high at other states   |

(1) Directions: I = input, O = output, OZ = 3-state output, OD = open-drain output, IO = input/output

#### Texas STRUMENTS

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## ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup> <sup>(2)</sup> <sup>(3)</sup>

|                      |                                      | MIN                         | MAX      | UNIT |
|----------------------|--------------------------------------|-----------------------------|----------|------|
| V <sub>MX</sub>      | Power supply voltage range           | -0.3                        | 35       | V    |
| V <sub>CC</sub>      | Power supply voltage range           | -0.3                        | 7        | V    |
|                      | Digital pin voltage range            | -0.5                        | 7        | V    |
| V <sub>REF</sub>     | Input voltage range                  | –0.3 V                      | $V_{CC}$ | V    |
|                      | ISENSEx pin voltage range            | -0.3                        | 0.5      | V    |
| I <sub>O(peak)</sub> | Peak motor drive output current      | Internally limited          |          |      |
| PD                   | Continuous total power dissipation   | See Thermal Information tab |          |      |
| TJ                   | Operating junction temperature range | -40                         | 150      | °C   |
| T <sub>stg</sub>     | Storage temperature range            | -60                         | 150      | °C   |

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to network ground terminal.

(3) Power dissipation and thermal limits must be observed.

### THERMAL INFORMATION

|                    |   | DRV8818 |        |
|--------------------|---|---------|--------|
|                    | THERMAL METRIC <sup>(1)</sup>                               | PWP     | UNITS  |
|                    |   | 28 PINS |        |
| θ <sub>JA</sub>    | Junction-to-ambient thermal resistance <sup>(2)</sup>       | 32.2    |        |
| θ <sub>JCtop</sub> | Junction-to-case (top) thermal resistance <sup>(3)</sup>    | 16.3    |        |
| $\theta_{JB}$      | Junction-to-board thermal resistance <sup>(4)</sup>         | 14      | °C 111 |
| $\Psi_{JT}$        | Junction-to-top characterization parameter <sup>(5)</sup>   | 0.5     | °C/W   |
| Ψ <sub>JB</sub>    | Junction-to-board characterization parameter <sup>(6)</sup> | 13.8    |        |
| θ <sub>JCbot</sub> | Junction-to-case (bottom) thermal resistance <sup>(7)</sup> | 2.1     |        |

For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, SPRA953.
 The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as

specified in JESD51-7, in an environment described in JESD51-2a.
(3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC-standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.

(4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.

(5) The junction-to-top characterization parameter,  $\psi_{JT}$ , estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining  $\theta_{JA}$ , using a procedure described in JESD51-2a (sections 6 and 7).

(6) The junction-to-board characterization parameter,  $\psi_{JB}$ , estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining  $\theta_{JA}$ , using a procedure described in JESD51-2a (sections 6 and 7).

(7) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.



## **RECOMMENDED OPERATING CONDITIONS**

| $T_{A} = 25$    | °C (unless otherwise noted)                     |     |     |          |      |
|-----------------|---|-----|-----|----------|------|
|                 |   | MIN | NOM | MAX      | UNIT |
| VM              | Motor power supply voltage range <sup>(1)</sup> | 8   |     | 35       | V    |
| V <sub>CC</sub> | Logic power supply voltage range                | 3   |     | 5.5      | V    |
| $V_{REF}$       | VREF input voltage                              | 0   |     | $V_{CC}$ | V    |
| R <sub>X</sub>  | R <sub>X</sub> resistance value                 | 12  | 56  | 100      | kΩ   |
| C <sub>X</sub>  | C <sub>X</sub> capacitance value                | 470 | 680 | 1500     | pF   |

(1) All  $V_{\rm M}$  pins must be connected to the same supply voltage.

## **ELECTRICAL CHARACTERISTICS**

#### $T_A = 25^{\circ}C$ (unless otherwise noted)

|                     | PARAMETER                                    | TEST CONDITIONS   | MIN                 | TYP        | MAX                 | UNIT |
|---------------------|--|---|---------------------|------------|---------------------|------|
| Power \$            | Supplies                                     |   |                     |            |                     |      |
| $I_{VM}$            | V <sub>M</sub> operating supply current      | V <sub>M</sub> = 35 V, f <sub>PWM</sub> < 50 KHz                          |                     | 7          | 10                  | mA   |
| I <sub>VCC</sub>    | V <sub>CC</sub> operating supply current     | f <sub>PWM</sub> < 50 KHz   |                     | 0.4        | 4                   | mA   |
| I <sub>VMQ</sub>    | V <sub>M</sub> sleep mode supply current     | V <sub>M</sub> = 35 V   |                     | 3          | 20                  | μA   |
| IVCCQ               | V <sub>CC</sub> sleep mode supply current    |   |                     | 0.5        | 20                  | μA   |
| V                   | V <sub>M</sub> undervoltage lockout voltage  | V <sub>M</sub> rising   |                     | 6.7        | 7.5                 | V    |
| V <sub>UVLO</sub>   | V <sub>CC</sub> undervoltage lockout voltage | V <sub>CC</sub> rising  |                     | 2.75       | 2.95                | V    |
| VREF Ir             | nput/Current Control Accuracy                |   | "                   |            |                     |      |
| I <sub>REF</sub>    | VREF input current                           | VREF = 3.3 V  | -3                  |            | 3                   | μA   |
| A 1                 | Chapping surrent assures                     | VREF = 2.0 V, 70% to 100% current   | -5                  |            | 5                   | %    |
| ∆I <sub>CHOP</sub>  | Chopping current accuracy                    | VREF = 2.0 V, 20% to 56% current  | -10                 |            | 10                  | %    |
| Logic-L             | evel Inputs                                  |   |                     |            |                     |      |
| VIL                 | Input low voltage                            |   |                     |            | $0.3 \times V_{CC}$ | V    |
| VIH                 | Input high voltage                           |   | $0.7 \times V_{CC}$ |            |                     | V    |
| V <sub>HYS</sub>    | Input hysteresis                             |   |                     | 300        |                     | mV   |
| I <sub>IL</sub>     | Input low current                            | $VIN = 0.3 \times V_{CC}$   | -20                 |            | 20                  | μA   |
| I <sub>IH</sub>     | Input high current                           | $VIN = 0.3 \times V_{CC}$   | -20                 |            | 20                  | μA   |
| R <sub>PU</sub>     | Pullup resistance                            |   |                     | 1          |                     | MΩ   |
| R <sub>PD</sub>     | Pulldown resistance                          |   |                     | 1          |                     | MΩ   |
| HOMEn               | Output                                       |   |                     |            |                     |      |
| V <sub>OL</sub>     | Output low voltage                           | I <sub>O</sub> = 200 μA   |                     |            | 0.3 × VCC           | V    |
| V <sub>OH</sub>     | Output high voltage                          | I <sub>O</sub> = -200 μA  | 0.7 × VCC           |            |                     | V    |
| Decay I             | nput   |   | "                   |            |                     |      |
| VIL                 | Input low threshold voltage                  | For fast decay mode   |                     | 0.21 × VCC |                     | V    |
| VIH                 | Input high threshold voltage                 | For slow decay mode   |                     | 0.6 × VCC  |                     | V    |
| H-Bridg             | je FETS                                      |   |                     |            |                     |      |
| R <sub>ds(on)</sub> | HS FET on resistance                         | $V_{M} = 24 \text{ V}, I_{O} = 2.5 \text{ A}, T_{J} = 25^{\circ}\text{C}$ |                     | 0.22       | 0.30                | Ω    |
| R <sub>ds(on)</sub> | LS FET on resistance                         | $V_{M} = 24 \text{ V}, I_{O} = 2.5 \text{ A}, T_{J} = 25^{\circ}\text{C}$ |                     | 0.15       | 0.24                | Ω    |
| I <sub>OFF</sub>    |  |   | -20                 |            | 20                  | μA   |
| Motor D             | Driver                                       |   |                     |            |                     |      |
| t <sub>OFF</sub>    | Off time                                     | Rx = 56 kΩ, Cx = 680 pF   | 35                  | 44         | 53                  | μs   |
| t <sub>BLANK</sub>  | Current sense blanking time                  | Rx = 56 kΩ, Cx = 680 pF   | 900                 | 1250       | 1500                | ns   |
| t <sub>DT</sub>     | Dead time                                    | SRn = 0   | 100                 | 475        | 800                 | ns   |
| t <sub>R</sub>      | Rise time                                    |   | 10                  |            | 80                  | ns   |
| t <sub>F</sub>      | Fall time                                    |   | 10                  |            | 80                  | ns   |



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## ELECTRICAL CHARACTERISTICS (continued)

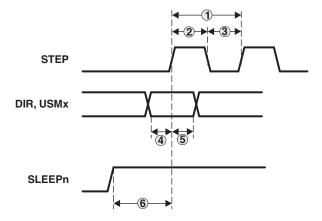
 $T_A = 25^{\circ}C$  (unless otherwise noted)

|                  | PARAMETER                    | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------|------------------------------|-----------------|-----|-----|-----|------|
| Protect          | tion Circuits                |                 |     |     |     |      |
| T <sub>TSD</sub> | Thermal shutdown temperature | Die temperature | 150 | 160 | 180 | °C   |
| I <sub>OCP</sub> | Overcurrent protection level |                 | 3.5 |     |     | А    |
| t <sub>OCP</sub> | OCP deglitch time            |                 |     | 1.5 |     | μs   |
| t <sub>RET</sub> | OCP retry time               |                 |     | 800 |     | μs   |

## TIMING REQUIREMENTS

 $T_A = 25^{\circ}C$  (unless otherwise noted)

|                       | PARAMETER                            |     |     |     |  |  |
|-----------------------|--------------------------------------|-----|-----|-----|--|--|
| f <sub>STEP</sub>     | Step frequency                       |     | 500 | kHz |  |  |
| t <sub>WH(STEP)</sub> | Pulse duration, STEP high            | 1   |     | μs  |  |  |
| t <sub>WL(STEP)</sub> | Pulse duration, STEP low             | 1   |     | μs  |  |  |
| t <sub>SU(STEP)</sub> | Setup time, command to STEP rising   | 200 |     | ns  |  |  |
| t <sub>H(STEP)</sub>  | Hold time, command to STEP rising    | 200 |     | ns  |  |  |
| t <sub>WAKE</sub>     | Wakeup time, SLEEPn inactive to STEP | 1.5 |     | ms  |  |  |



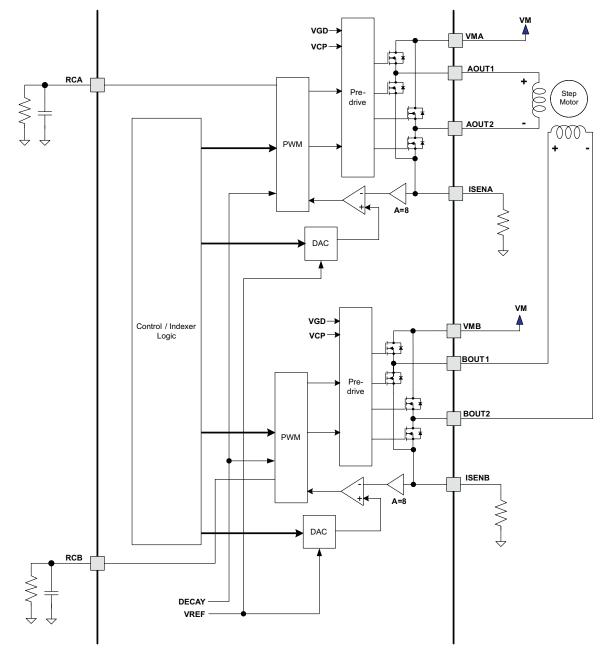


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### **FUNCTIONAL DESCRIPTION**

## **PWM H-Bridge Drivers**

DRV8818 contains two H-bridge motor drivers with current-control PWM circuitry, and a microstepping indexer. A block diagram of the motor control circuitry is shown below.





#### **Current Regulation**

The PWM chopping current is set by a comparator, which compares the voltage across a current sense resistor, multiplied by a factor of 8, with a reference voltage. The reference voltage is input from the VREF pin. The full-scale (100%) chopping current is calculated as follows:

$$I_{CHOP} = \frac{V_{REFX}}{8 \bullet R_{ISENSE}}$$

Example:

If a 0.22- $\Omega$  sense resistor is used and the VREFx pin is 3.3 V, the full-scale (100%) chopping current is 3.3 V/(8 \* 0.22  $\Omega$ ) = 1.875 A.

The reference voltage is also scaled by an internal DAC that allows torque control for fractional stepping of a bipolar stepper motor, as described in the "Microstepping Indexer" section below.

When a winding is activated, the current through it rises until it reaches the chopping current threshold described above, then the current is switched off for a fixed off time. The off time is determined by the values of a resistor and capacitor connected to the RCA (for bridge A) and RCB (for bridge B) pins. The off time is approximated by:

$$t_{OFF} = R \bullet C$$

To avoid falsely tripping on transient currents when the winding is first activated, a blanking period is used immediately after turning on the FETs, during which the state of the current sense comparator is ignored. The blanking time is determined by the value of the capacitor connected to the RCx pin and is approximated by:

$$t_{\scriptscriptstyle BLANK} = 1400 \bullet C$$

### Decay Mode

During PWM current chopping, the H-bridge is enabled to drive through the motor winding until the PWM current chopping threshold is reached. This is shown in Figure 2, Item 1. The current flow direction shown indicates positive current flow in the step table below.

Once the chopping current threshold is reached, the H-bridge can operate in two different states, fast decay or slow decay.

In fast decay mode, once the PWM chopping current level has been reached, the H-bridge reverses state to allow winding current to flow in a reverse direction. If synchronous rectification is enabled (SRn pin logic low), the opposite FETs are turned on; as the winding current approaches zero, the bridge is disabled to prevent any reverse current flow. If SRn is high, current is recirculated through the body diodes, or through external Schottky diodes. Fast-decay mode is shown in Figure 2, Item 2.

In slow-decay mode, winding current is re-circulated by enabling both of the low-side FETs in the bridge. This is shown in Figure 2, Item 3.

If SRn is high, current is recirculated only through the body diodes, or through external Schottky diodes. In this case fast decay is always used.

TEXAS INSTRUMENTS

y: (2)

(1)



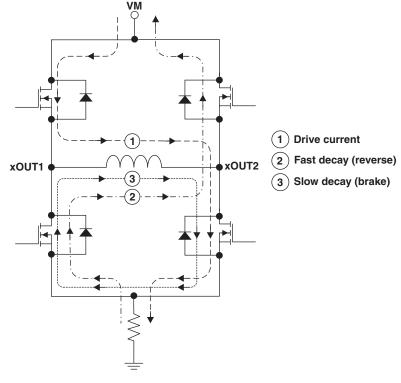


Figure 2. Decay Mode

The DRV8818 also supports a mixed decay mode. Mixed decay mode begins as fast decay, but after a period of time switches to slow decay mode for the remainder of the fixed off time.

Fast and mixed decay modes are only active if the current through the winding is decreasing; if the current is increasing, then slow decay is always used.

Which decay mode is used is selected by the voltage on the DECAY pin. If the voltage is greater than 0.6 x  $V_{CC}$ , slow decay mode is always used. If DECAY is less than 0.21 x  $V_{CC}$ , the device operates in fast decay mode when the current through the winding is decreasing. If the voltage is between these levels, mixed decay mode is enabled.

In mixed decay mode, the voltage on the DECAY pin sets the point in the cycle that the change to slow decay mode occurs. This time can be approximated by:

$$t_{FD} = R \bullet C \bullet In \left( \frac{0.6 \bullet V_{CC}}{V_{DECAY}} \right)$$

(4)

Mixed decay mode is only used while the current though the winding is decreasing; slow decay is used while the current is increasing.

Operation of the blanking, fixed off time, and mixed decay mode is illustrated in Figure 3.



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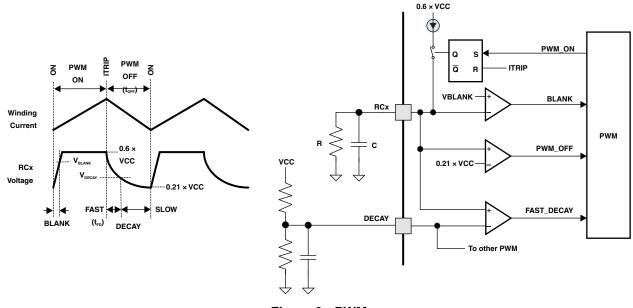


Figure 3. PWM

#### **Microstepping Indexer**

Built-in indexer logic in the DRV8818 allows a number of different stepping configurations. The USM1 and USM0 pins are used to configure the stepping format as shown in the table below:

| USM1 | USM0 | STEP MODE                        |
|------|------|----------------------------------|
| 0    | 0    | Full step (2-phase excitation)   |
| 0    | 1    | 1/2 step (1-2 phase excitation)  |
| 1    | 0    | 1/4 step (W1-2 phase excitation) |
| 1    | 1    | Eight microsteps/steps           |

The following table shows the relative current and step directions for different settings of USM1 and USM0. At each rising edge of the STEP input, the indexer travels to the next state in the table. The direction is shown with the DIR pin high; if the DIR pin is low the sequence is reversed. Positive current is defined as xOUT1 = positive with respect to xOUT2.

Note that the home state is 45 degrees. This state is entered at power-up or device reset. The HOMEn output pin is driven low in this state. In all other states it is driven logic high.



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| FULL STEP<br>USM = 00 | 1/2 STEP<br>USM = 01 | 1/4 STEP<br>USM = 10 | 1/8 STEP<br>USM = 11 | AOUTx<br>CURRENT<br>(% FULL-SCALE) | BOUTx<br>CURRENT<br>(% FULL-SCALE) | STEP ANGLE<br>(DEGREES) |
|-----------------------|----------------------|----------------------|----------------------|------------------------------------|------------------------------------|-------------------------|
|                       | 1                    | 1                    | 1                    | 100                                | 0                                  | 0                       |
|                       |                      |                      | 2                    | 98                                 | 20                                 | 11.325                  |
|                       |                      | 2                    | 3                    | 92                                 | 38                                 | 22.5                    |
|                       |                      |                      | 4                    | 83                                 | 56                                 | 33.75                   |
| 1                     | 2                    | 3                    | 5                    | 71                                 | 71                                 | 45 (home state)         |
|                       |                      |                      | 6                    | 56                                 | 83                                 | 56.25                   |
|                       |                      | 4                    | 7                    | 38                                 | 92                                 | 67.5                    |
|                       |                      |                      | 8                    | 20                                 | 98                                 | 78.75                   |
|                       | 3                    | 5                    | 9                    | 0                                  | 100                                | 90                      |
|                       |                      |                      | 10                   | -20                                | 98                                 | 101.25                  |
|                       |                      | 6                    | 11                   | -38                                | 92                                 | 112.5                   |
|                       |                      |                      | 12                   | -56                                | 83                                 | 123.75                  |
| 2                     | 4                    | 7                    | 13                   | -71                                | 71                                 | 135                     |
|                       |                      |                      | 14                   | -83                                | 56                                 | 146.25                  |
|                       |                      | 8                    | 15                   | -92                                | 38                                 | 157.5                   |
|                       |                      |                      | 16                   | -98                                | 20                                 | 168.75                  |
|                       | 5                    | 9                    | 17                   | -100                               | 0                                  | 180                     |
|                       |                      |                      | 18                   | -98                                | -20                                | 191.25                  |
|                       |                      | 10                   | 19                   | -92                                | -38                                | 202.5                   |
|                       |                      |                      | 20                   | -83                                | -56                                | 213.75                  |
| 3                     | 6                    | 11                   | 21                   | -71                                | -71                                | 225                     |
|                       |                      |                      | 22                   | -56                                | -83                                | 236.25                  |
|                       |                      | 12                   | 23                   | -38                                | -92                                | 247.5                   |
|                       |                      |                      | 24                   | -20                                | -98                                | 258.75                  |
|                       | 7                    | 13                   | 25                   | 0                                  | -100                               | 270                     |
|                       |                      |                      | 26                   | 20                                 | -98                                | 281.25                  |
|                       |                      | 14                   | 27                   | 38                                 | -92                                | 292.5                   |
|                       |                      |                      | 28                   | 56                                 | -83                                | 303.75                  |
| 4                     | 8                    | 15                   | 29                   | 71                                 | -71                                | 315                     |
|                       |                      |                      | 30                   | 83                                 | -56                                | 326.25                  |
|                       |                      | 16                   | 31                   | 92                                 | -38                                | 337.5                   |
|                       |                      |                      | 32                   | 98                                 | -20                                | 348.75                  |

#### **RESETn, ENABLEn and SLEEPn Operation**

The RESETn pin, when driven active low, resets the step table to the home position. It also disables the H-bridge drivers. The STEP input is ignored while RESETn is active.

The ENABLEn pin is used to control the output drivers. When ENABLEn is low, the output H-bridges are enabled. When ENABLEn is high, the H-bridges are disabled and the outputs are in a high-impedance state.

Note that when ENABLEn is high, the input pins and control logic, including the indexer (STEP and DIR pins) are still functional.

The SLEEPn pin is used to put the device into a low power state. If SLEEPn is low, the H-bridges are disabled, the gate drive charge pump is stopped, and all internal clocks are stopped. In this state all inputs are ignored until the SLEEPn pin returns high.



#### **Protection Circuits**

#### **Overcurrent Protection (OCP)**

If the current through any FET exceeds the preset overcurrent threshold, all FETs in the H-bridge will be disabled for a period of approximately 800 µs, or until the ENABLEn pin has been brought inactive high and then back low, or power is removed and re-applied. Overcurrent conditions are sensed in both directions; i.e., a short to ground, supply, or across the motor winding will all result in an overcurrent shutdown.

Note that overcurrent protection does not use the current sense circuitry used for PWM current control and is independent of the Isense resistor value or VREF voltage.

#### **Thermal Shutdown (TSD)**

If the die temperature exceeds safe limits, all drivers in the device are shut down and the indexer is reset to the home state. Once the die temperature has fallen to a safe level operation resumes.

#### Undervoltage Lockout (UVLO)

If at any time the voltage on the VM or VCC pins falls below the VM or VCC undervoltage lockout threshold voltage, all circuitry in the device will be disabled, and the indexer will be reset to the home state. Operation will resume when VM and VCC both rise above their UVLO thresholds.



### THERMAL INFORMATION

#### Thermal Protection

The DRV8818 has thermal shutdown (TSD) as described above. If the die temperature exceeds approximately 150°C, the device will be disabled until the temperature drops to a safe level.

Any tendency of the device to enter thermal shutdown is an indication of either excessive power dissipation, insufficient heatsinking, or too high an ambient temperature.

#### **Power Dissipation**

Power dissipation in the DRV8818 is dominated by the power dissipated in the output FET resistance, or  $R_{DS(ON)}$ . Average power dissipation when running a stepper motor can be roughly estimated by:

$$P_{TOT} = 4 \bullet R_{DS(ON)} \bullet (I_{OUT(RMS)})^2$$

(5)

where  $P_{TOT}$  is the total power dissipation,  $R_{DS(ON)}$  is the resistance of each FET, and  $I_{OUT(RMS)}$  is the RMS output current being applied to each winding.  $I_{OUT(RMS)}$  is equal to the approximately 0.7x the full-scale output current setting. The factor of 4 comes from the fact that there are two motor windings, and at any instant two FETs are conducting winding current for each winding (one high-side and one low-side).

The maximum amount of power that can be dissipated in the DRV8818 is dependent on ambient temperature and heatsinking. The thermal dissipation ratings table in the datasheet can be used to estimate the temperature rise for typical PCB constructions.

Note that  $R_{DS(ON)}$  increases with temperature, so as the device heats, the power dissipation increases. This must be taken into consideration when sizing the heatsink.

#### Heatsinking

The PowerPAD<sup>™</sup> package uses an exposed pad to remove heat from the device. For proper operation, this pad must be thermally connected to copper on the PCB to dissipate heat. On a multi-layer PCB with a ground plane, this can be accomplished by adding a number of vias to connect the thermal pad to the ground plane. On PCBs without internal planes, copper area can be added on either side of the PCB to dissipate heat. If the copper area is on the opposite side of the PCB from the device, thermal vias are used to transfer the heat between top and bottom layers.

For details about how to design the PCB, refer to TI Application Report SLMA002, " PowerPAD<sup>™</sup> Thermally Enhanced Package" and TI Application Brief SLMA004, " PowerPAD<sup>™</sup> Made Easy", available at www.ti.com.

In general, the more copper area that can be provided, the more power can be dissipated.



## PACKAGING INFORMATION

| Orderable Device | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2) | Lead finish/<br>Ball material<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|---------|
| DRV8818PWP       | ACTIVE        | HTSSOP       | PWP                | 28   | 50             | RoHS & Green    | NIPDAU                               | Level-3-260C-168 HR  | -40 to 85    | DRV8818                 | Samples |
| DRV8818PWPR      | ACTIVE        | HTSSOP       | PWP                | 28   | 2000           | RoHS & Green    | NIPDAU                               | Level-3-260C-168 HR  | -40 to 85    | DRV8818                 | Samples |

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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## PACKAGE OPTION ADDENDUM

10-Dec-2020

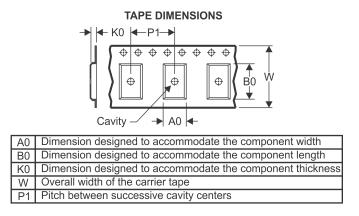
## PACKAGE MATERIALS INFORMATION

www.ti.com

Texas Instruments

## TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| *All dimensions are nor | ninal |
|-------------------------|-------|
|-------------------------|-------|

| Device      | Package<br>Type | Package<br>Drawing |    | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|-------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| DRV8818PWPR | HTSSOP          | PWP                | 28 | 2000 | 330.0                    | 16.4                     | 6.9        | 10.2       | 1.8        | 12.0       | 16.0      | Q1               |

TEXAS INSTRUMENTS

www.ti.com

## PACKAGE MATERIALS INFORMATION

26-Feb-2019



\*All dimensions are nominal

| Device      | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|-------------|--------------|-----------------|------|------|-------------|------------|-------------|
| DRV8818PWPR | HTSSOP       | PWP             | 28   | 2000 | 350.0       | 350.0      | 43.0        |

## **PWP 28**

## **GENERIC PACKAGE VIEW**

## PowerPAD<sup>™</sup> TSSOP - 1.2 mm max height

4.4 x 9.7, 0.65 mm pitch

SMALL OUTLINE PACKAGE

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

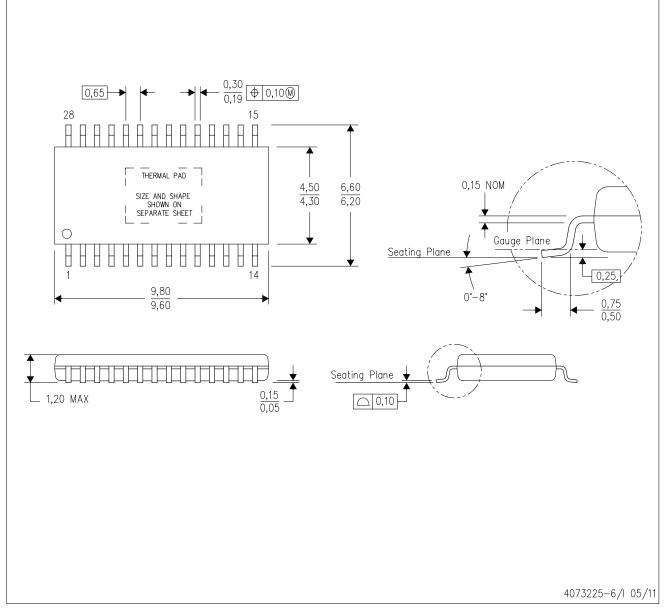




4224765/B

PWP (R-PDSO-G28)

PowerPAD<sup>™</sup> PLASTIC SMALL OUTLINE



All linear dimensions are in millimeters. NOTES: Α.

- Β. This drawing is subject to change without notice.
- Body dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.15 per side. C.
- This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad D.
- Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <a href="http://www.ti.com">http://www.ti.com</a>. E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions. E. Falls within JEDEC MO-153

PowerPAD is a trademark of Texas Instruments.



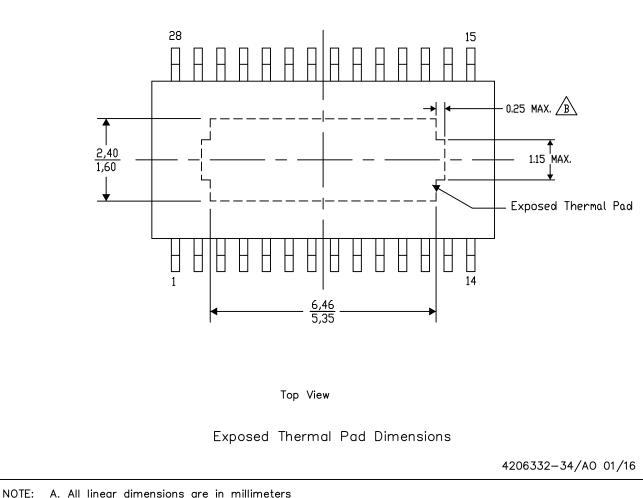
# PWP (R-PDSO-G28) PowerPAD<sup>™</sup> SMALL PLASTIC OUTLINE

#### THERMAL INFORMATION

This PowerPAD<sup>™</sup> package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

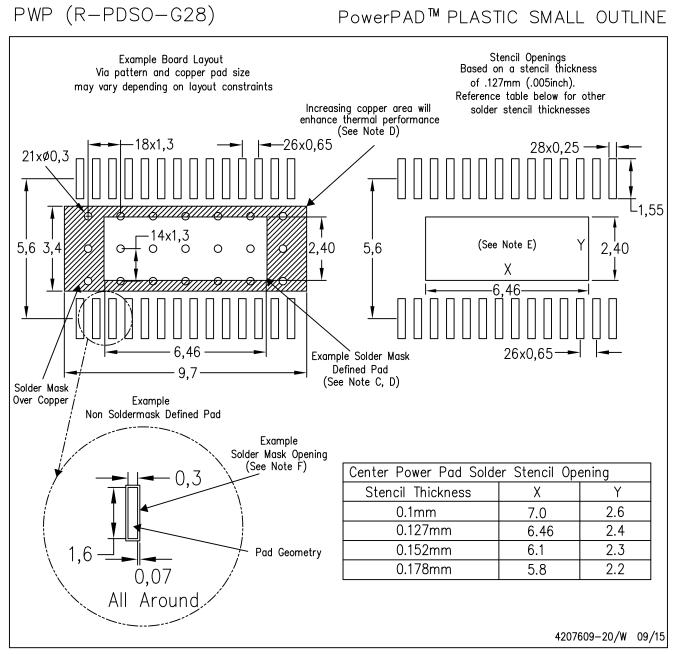
The exposed thermal pad dimensions for this package are shown in the following illustration.



TE: A. All linear dimensions are in millimeters B. Exposed tie strap features may not be present.

PowerPAD is a trademark of Texas Instruments





NOTES:

Α.

B. This drawing is subject to change without notice.

All linear dimensions are in millimeters.

- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
- F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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